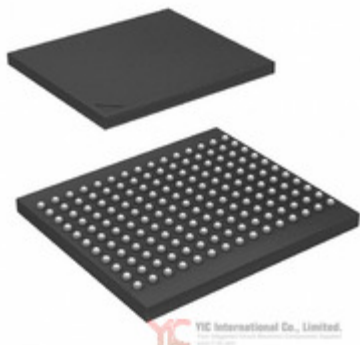


| | |
|---|---|
|  | <h2 style="color: #E67E22;">71V65703S80BQ</h2> |
| | <p>Hersteller-Teilenummer: 71V65703S80BQ</p> <p>Hersteller / Marke: IDT (Integrated Device Technology)</p> <p>Teil der Beschreibung: IC SRAM 9MBIT 8NS 165CABGA</p> <p>Datenblätter: 1.71V65703S80BQ.pdf 2.71V65703S80BQ.pdf</p> <p>RoHs Status: Enthält Blei / RoHS nicht konform</p> <p>Lagerzustand: New original, Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
|  | |
| <p>Image may be representation. See specs for product details.</p> | |

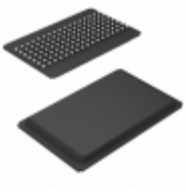
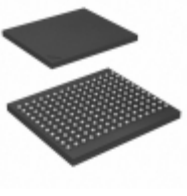
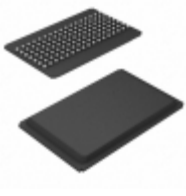
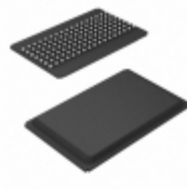
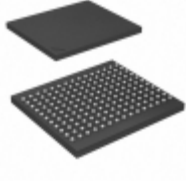
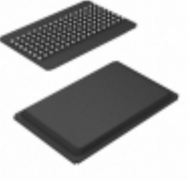

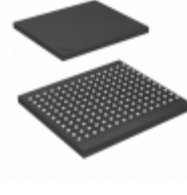
Spezifikationen

| | |
|-------------------------|--|
| Teilenummer | 71V65703S80BQ |
| Hersteller | IDT (Integrated Device Technology) |
| Beschreibung | IC SRAM 9MBIT 8NS 165CABGA |
| Kategorie | Integrierte Schaltungen (ICs) > Erinnerung |
| Teilstatus | Require For Quote & Check Stock |
| Spannungsversorgung | 3.135 V ~ 3.465 V |
| Supplier Device-Gehäuse | 165-CABGA (13x15) |
| Geschwindigkeit | 8ns |
| Serie | - |
| Verpackung | Tray |
| Verpackung / Gehäuse | 165-TBGA |
| Betriebstemperatur | 0°C ~ 70°C (TA) |
| Speichertyp | Volatile |
| SpeichergroÙe | 9Mb (256K x 36) |
| Speicherformat | SRAM |
| Schnittstelle | Parallel |

71V65703S80BQ Electronic Components ist ein 100% neues Original von YIC Distributor, 71V65703S80BQ-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, 71V65703S80BQ IDT (Integrated Device Technology) mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.

RFQ 71V65703S80BQ E-Mail: Info@Y-IC.com

Sie können auch interessiert

| | | | |
|---|---|---|--|
| <p>sein:</p>  <p>71V65703S80BGG8 IDT, Integrated Device Technology Inc IC SRAM 9MBIT 8NS 119BGA</p> |  <p>71V65703S80BQG18 IDT, Integrated Device Technology Inc IC SRAM 9MBIT 8NS 165CABGA</p> |  <p>71V65703S80BG8 IDT, Integrated Device Technology Inc IC SRAM 9MBIT 8NS 119BGA</p> |  <p>71V65703S80BG IDT, Integrated Device Technology Inc IC SRAM 9MBIT 8NS 119BGA</p> |
|  <p>71V65703S80BQG8 IDT, Integrated Device Technology Inc IC SRAM 9MBIT 8NS 165CABGA</p> |  <p>71V65703S80BGG IDT, Integrated Device Technology Inc IC SRAM 9MBIT 8NS 119BGA</p> |  <p>71V65703S75PFG18 IDT, Integrated Device Technology Inc IC SRAM 9MBIT 7.5NS 100TQFP</p> |  <p>71V65703S80BQGI IDT, Integrated Device Technology Inc IC SRAM 9MBIT 8NS 165CABGA</p> |

Verwandtes Hot-Keyword

Mehr

| | | | | |
|--|---------------------------|----------------------------|---------------------|------------------------------------|
| 71V65703S80BQ IDT (Integrated Device Technology) | 71V65703S80BQ Datenblatt | 71V65703S80BQ-Datenblätter | 71V65703S80BQ PDF | IDT (Integrated Device Technology) |
| 71V65703S80BQ Electronic | 71V65703S80BQ-Komponenten | 71V65703S80BQ-Verteiler | 71V65703S80BQ-Bild | 71V65703S80BQ-Teil |
| 71V65703S80BQ Preis | 71V65703S80BQ Hersteller | 71V65703S80BQ Bild | 71V65703S80BQ Aktie | 71V65703S80BQ Inventar |
| 71V65703S80BQ Neu | 71V65703S80BQ Original | 71V65703S80BQ garantiert | 71V65703S80BQ RFQ | 71V65703S80BQ Online bestellen |

Contact us: Info@Y-IC.com

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